onsemi

MOSFET – P-Channel, Logic Level, POWERTRENCH[®]

-40 V, -50 A, 13.5 m Ω

FDWS9510L-F085

Features

- Typ $R_{DS(on)} = 11 \text{ m}\Omega$ at $V_{GS} = -10 \text{ V}$; $I_D = -50 \text{ A}$
- Typ $Q_{g(tot)} = 28 \text{ nC}$ at $V_{GS} = -10 \text{ V}$; $I_D = -50 \text{ A}$
- UIS Capability
- Wettable Flanks for Automatic Optical Inspection (AOI)
- AEC-Q101 Qualified
- These Devices are Pb-Free and are RoHS Compliant

Applications

- Automotive Engine Control
- Powertrain Management
- Solenoid and Motor Drivers
- Electronic Steering
- Integrated Starter/Alternator
- Distributed Power Architectures and VRM
- Primary Switch for 12 V Systems

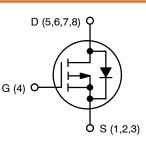
MAXIMUM RATINGS (T_J = 25° C unless otherwise noted)

Parameter		Symbol	Value	Unit	
Drain-to-Source Voltage		V _{DSS}	-40	V	
Gate-to-Source Voltage		V _{GS}	±16	V	
Continuous Drain Current (V _{GS} = 10 V) (Note 1)	rent $T_{C} = 25^{\circ}C$		-50	A	
Pulsed Drain Current	T _C = 25°C		See Figure 4		
Single Pulse Avalanche Energy (N	E _{AS}	32	mJ		
Power Dissipation		PD	75	W	
Derate above 25°C		0.5	W/°C		
Operating and Storage Temperature		T _J , T _{STG}	–55 to +175	°C	
Thermal Resistance (Junction-to-Case)		$R_{\theta JC}$	2	°C/W	
Maximum Thermal Resistance (Junction-to-Ambient) (Note 3)		R_{\thetaJA}	50	°C/W	

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- 1. Current is limited by wirebond configuration
- 2. Starting Tj = 25°C, L = 40 μ H, I_{AS} = -40 A, V_{DD} = -40 V during inductor charging and V_{DD} = 0 V during time in avalanche
- 3. $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. $R_{\theta JC}$ is guaranteed by design while $R_{\theta JA}$ is determined by the user's board design. The maximum rating presented here is based on mounting on a 1 in² pad of 2 oz copper.

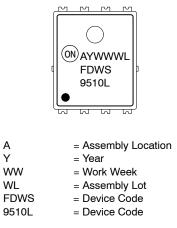
V _{DSS}	R _{DS(ON)} MAX	I _D MAX
–40 V	13.5 m Ω @ –10 V	–50 A



P-Channel MOSFET



MARKING DIAGRAM



(Note: Microdot may be in either location)

ORDERING INFORMATION

Device	Package	Shipping [†]
FDWS9510L-F085	DFNW8 (Power56) (Pb–Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_J = 25°C unless otherwise specified)

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
OFF CHARACTERISTICS							
B _{VDSS}	Drain-to-Source Breakdown Voltage	$I_D = -250 \ \mu A, \ V_{GS} = 0 \ V$		-40	-	-	V
I _{DSS}	Drain-to-Source Leakage Current	V _{DS} = -40 V, V _{GS} = 0 V	$T_J = 25^{\circ}C$	-	-	1	μA
		V _{GS} = 0 V	T _J = 175°C (Note 4)	-	-	1	mA
I _{GSS}	Gate-to-Source Leakage Current	$V_{GS} = \pm 16 V$		-	-	±100	nA

ON CHARACTERISTICS

V _{GS(th)}	Gate-to-Source Threshold Voltage	$V_{GS} = V_{DS}$, $I_D = -250 \ \mu A$		-1	-1.8	-3	V
R _{DS(on)}	Drain-to-Source On-Resistance	$I_D = -25$ A, $V_{GS} = -4.5$ V		-	18	23	mΩ
		$I_{\rm D} = -50 \rm A$	$T_{\rm J} = 25^{\circ}C$	-	11	13.5	mΩ
		V _{GS} = -10 V	T _J = 175°C (Note 4)	-	18.8	23	

DYNAMIC CHARACTERISTICS

C _{iss}	Input Capacitance	V_{DS} = -20 V, V_{GS} = 0 V, f = 1 MHz		-	2320	-	pF
C _{oss}	Output Capacitance			-	811	-	
C _{rss}	Reverse Transfer Capacitance			-	38	-	
Rg	Gate Resistance	V _{GS} = 0.5 V, f = 1 MHz		-	23	-	Ω
Q _{g(tot)}	Total Gate Charge	V_{GS} = 0 to -10 V		-	28	37	nC
Q _{g(th)}	Threshold Gate Charge	V_{GS} = 0 to -1 V		-	4	-	
Q _{gs}	Gate-to-Source Gate Charge	V _{DD} = -20 V, I _D = -50 A		-	7	-	
Q _{gd}	Gate-to-Drain "Miller" Charge	$I_{\rm D} = -50$ A		-	4	-	

SWITCHING CHARACTERISTICS

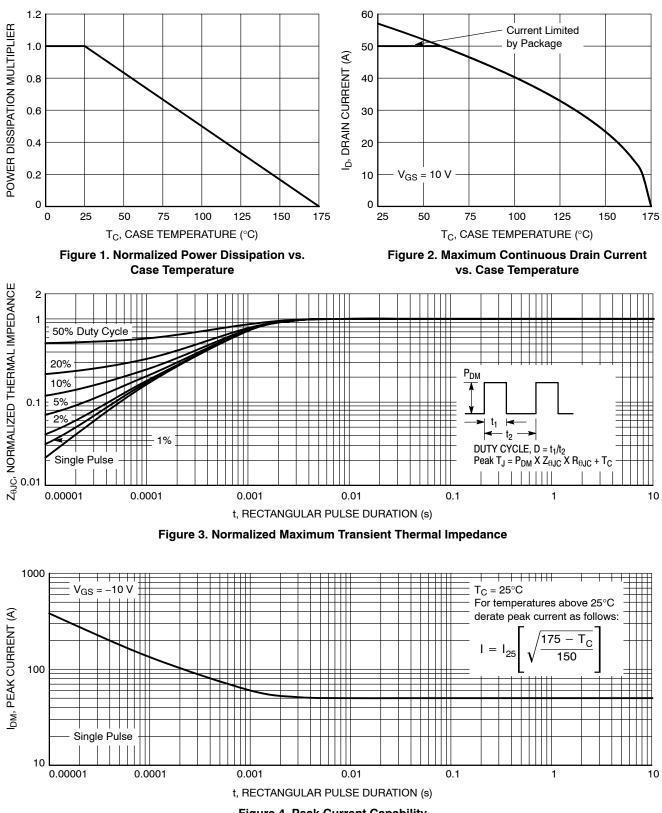
t _{on}	Turn-On Time	$V_{DD} = -20 \text{ V}, \text{ I}_{D} = -50 \text{ A},$	-	-	20	ns
t _{d(on)}	Turn-On Delay Time	V_{GS} = –10 V, R_{GEN} = 6 Ω	-	10	-	
t _r	Turn–On Rise Time		-	4	-	
t _{d(off)}	Turn-Off Delay Time		-	110	-	
t _f	Turn-Off Fall Time		-	37	-	
t _{off}	Turn-Off Time		-	-	222	

DRAIN-SOURCE DIODE CHARACTERISTICS

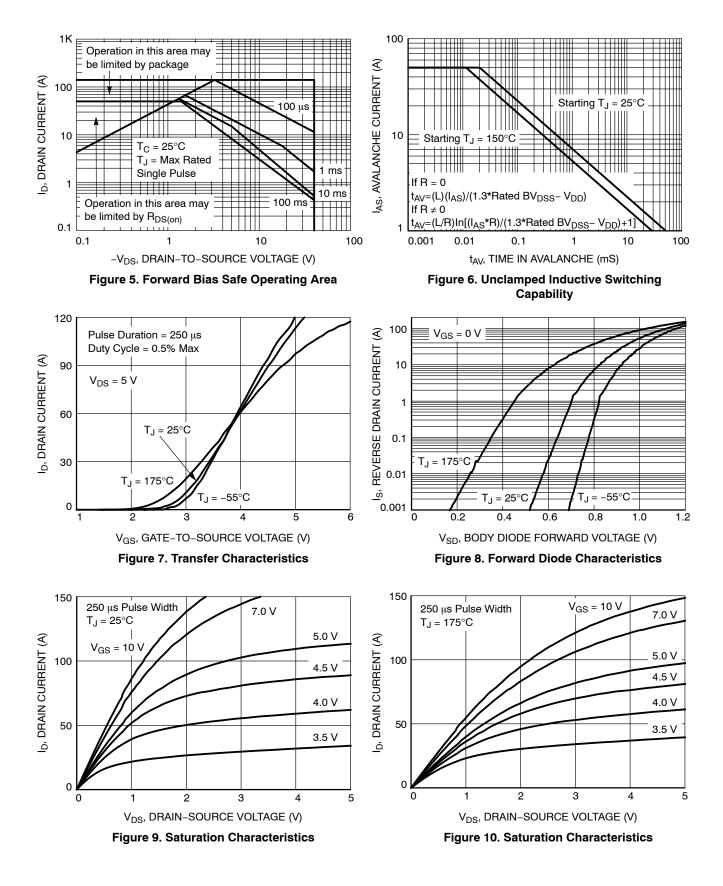
V _{SD}	Source-to-Drain Diode Voltage	$I_{SD} = -50 \text{ A}, \text{ V}_{GS} = 0 \text{ V}$	-	-1	-1.25	V
		I _{SD} = -25 A, V _{GS} = 0 V	-	-0.9	-1.2	
T _{rr}	Reverse Recovery Time	$I_F = -50$ A, $dI_{SD}/dt = 100$ A/ μ s	-	44	62	ns
Q _{rr}	Reverse Recovery Charge		-	31	47	nC

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 4. The maximum value is specified by design at $T_J = 175^{\circ}$ C. Product is not tested to this condition in production

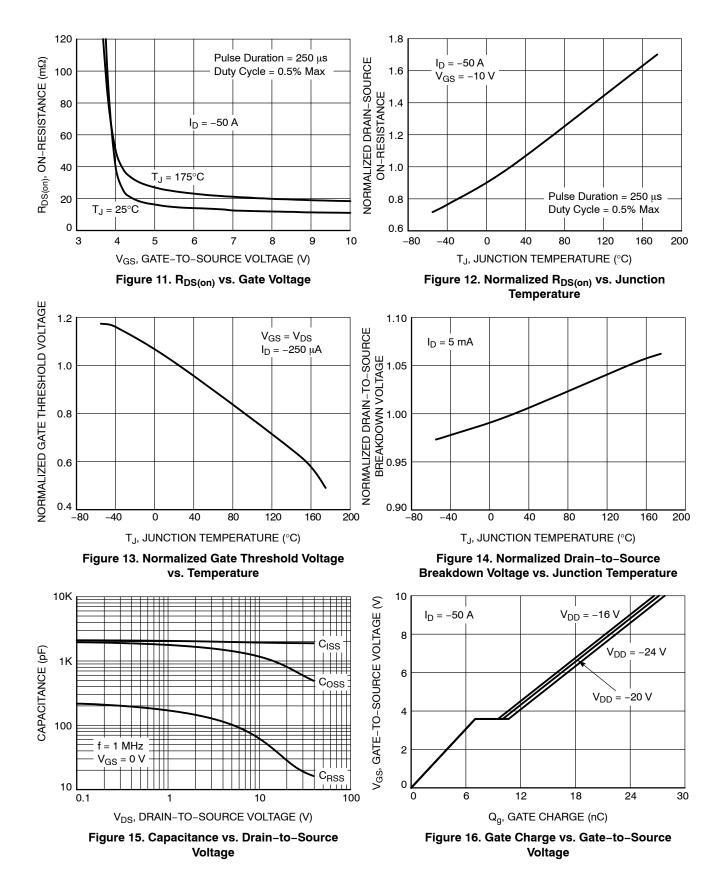
TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



TYPICAL CHARACTERISTICS



PACKAGE DIMENSIONS

DFNW8 5.2x6.3, 1.27P CASE 507AU **ISSUE A**

> (5.10) 4.42

DIM

А

A1

A2

A3

b

b1

b2

D

D1

D2

Е

E1

E2

E3

E4

е

k

L

z

z1 θ

e/2

MIN.

0.90

0.65

0.47

0.13

5.00

4.80

3.72

6.20

5.70

3.38

1.30

0.64

0.24

0°

3.91

1.27

5

网

0.92

1 22-

MILLIMETERS

NOM.

1.00

0.75

0.30 REF

0.52

0.18

(0.54)

5.10

4.90

3.82

6.30

5.80

3.48

0.30 REF

0.45 REF

1.27 BSC

0.635BSC

1.40

0.74

0.29

(0.28)

MAX.

1.10

0.05

0.85

0.57

0.23

5.20

5.00

3.92

6.40

5.90

3.58

1.50

0.84

0.34

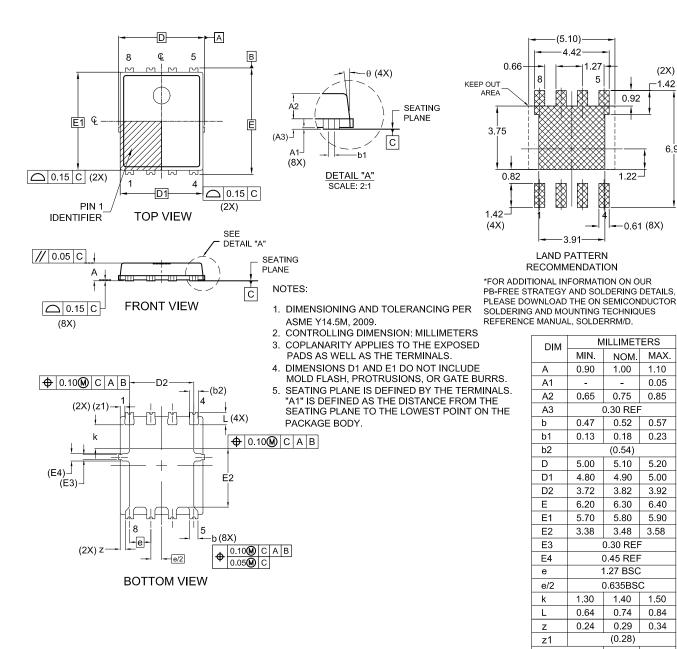
12°

-0.61 (8X)

(2X)

-1.42

6.91



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